

1.5V Drive Pch MOSFET

RW1A013ZP

●Structure

Silicon P-channel MOSFET

●Features

- 1) Low on-resistance.
- 2) High power package.
- 3) Low voltage drive. (1.5V)

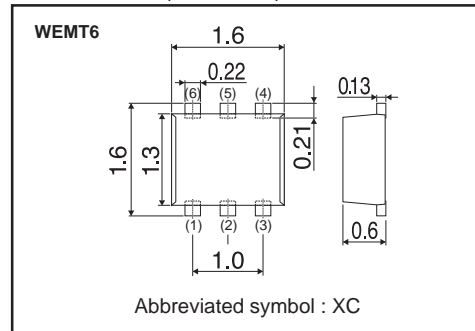
●Application

Switching

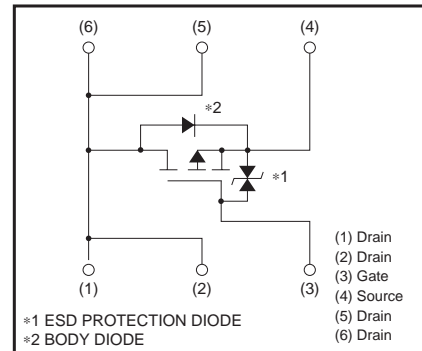
●Packaging specifications

Type	Package	Taping
	Code	T2R
	Basic ordering unit (pieces)	8000
RW1A013ZP		○

●Dimensions (Unit : mm)



●Inner circuit



●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Drain-source voltage	V_{DSS}	-12	V	
Gate-source voltage	V_{GSS}	±10	V	
Drain current	Continuous	I_D	±1.3	A
	Pulsed	I_{DP} *1	±2.6	A
Source current (Body diode)	Continuous	I_S	-0.5	A
	Pulsed	I_{SP} *1	-2.6	A
Total power dissipation	P_D *2	0.7	W	
Channel temperature	T_{ch}	150	°C	
Range of Storage temperature	T_{stg}	-55 to +150	°C	

*1 $P_w \leq 10\mu s$, Duty cycle $\leq 1\%$

*2 When mounted on a ceramic board

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th(ch-a)}$ *	179	°C / W

* When mounted on a ceramic board

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	-	-	±10	μA	V _{GS} =±10V, V _{DS} =0V
Drain-source breakdown voltage	V _{(BR)DSS}	-12	-	-	V	I _D =-1mA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}	-	-	-1	μA	V _{DS} =-12V, V _{GS} =0V
Gate threshold voltage	V _{GS(th)}	-0.3	-	-1.0	V	V _{DS} =-6V, I _D =-1mA
Static drain-source on-state resistance	R _{DS(on)} *	-	190	260	mΩ	I _D =-1.3A, V _{GS} =-4.5V
		-	280	390	mΩ	I _D =-0.6A, V _{GS} =-2.5V
		-	400	600	mΩ	I _D =-0.6A, V _{GS} =-1.8V
		-	530	1060	mΩ	I _D =-0.2A, V _{GS} =-1.5V
Forward transfer admittance	Y _{fs} *	1.4	-	-	S	V _{DS} =-6V, I _D =-1.3A
Input capacitance	C _{iss}	-	290	-	pF	V _{DS} =-6V
Output capacitance	C _{oss}	-	28	-	pF	V _{GS} =0V
Reverse transfer capacitance	C _{rss}	-	21	-	pF	f=1MHz
Turn-on delay time	t _{d(on)} *	-	8	-	ns	V _{DD} ≐-6V
Rise time	t _r *	-	10	-	ns	I _D =-0.6A
Turn-off delay time	t _{d(off)} *	-	30	-	ns	V _{GS} =-4.5V
Fall time	t _f *	-	9	-	ns	R _L ≐10Ω
Total gate charge	Q _g *	-	2.4	-	nC	V _{DD} ≐-6V R _L ≐4.6Ω
Gate-source charge	Q _{gs} *	-	0.6	-	nC	I _D =-1.3A R _G =10Ω
Gate-drain charge	Q _{gd} *	-	0.4	-	nC	V _{GS} =-4.5V

*Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V _{SD} *	-	-	-1.2	V	I _S =-1.3A, V _{GS} =0V

*Pulsed

●Electrical characteristics

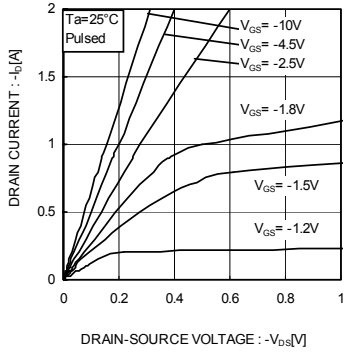


Fig.1 Typical Output Characteristics(I)

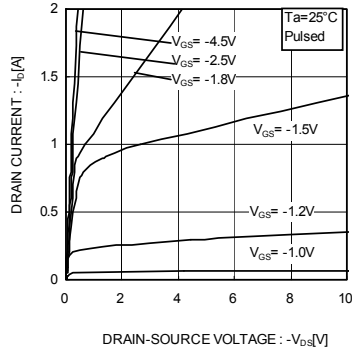


Fig.2 Typical Output Characteristics(II)

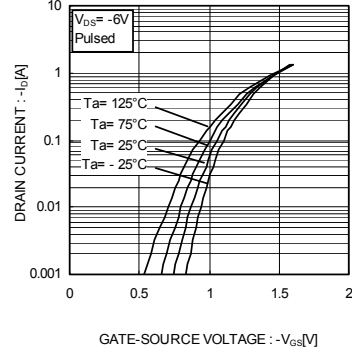


Fig.3 Typical Transfer Characteristics

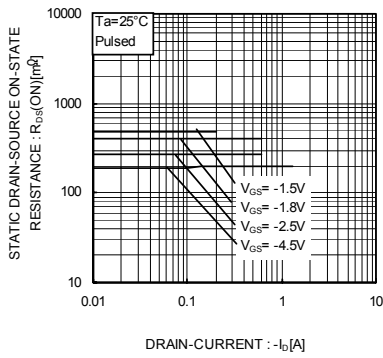


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current(I)

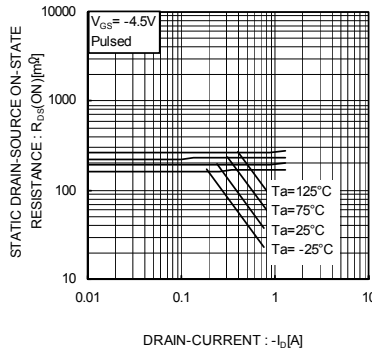


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II)

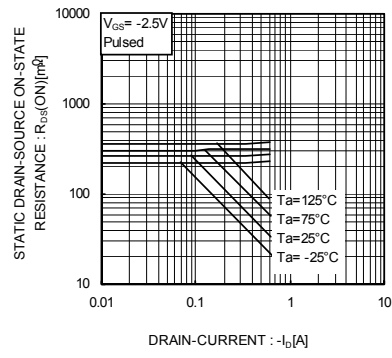


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(III)

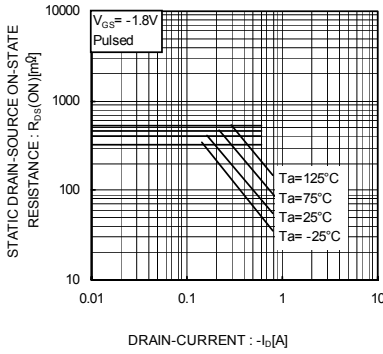


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current(IV)

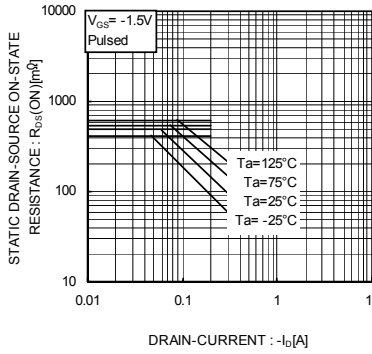


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current(V)

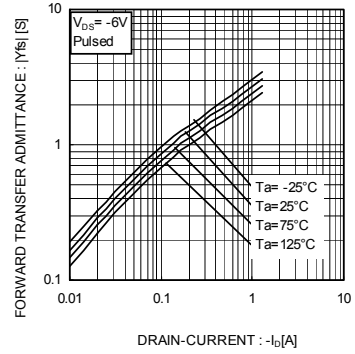


Fig.9 Forward Transfer Admittance vs. Drain Current

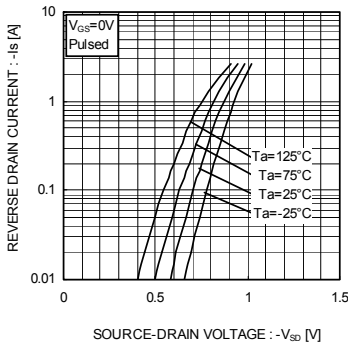


Fig.10 Reverse Drain Current vs. Source-Drain Voltage

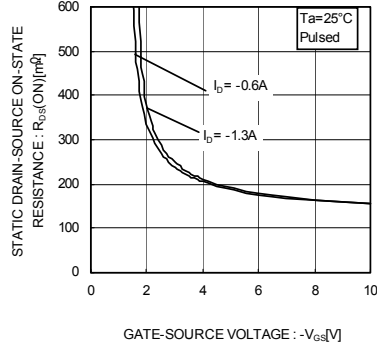


Fig.11 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

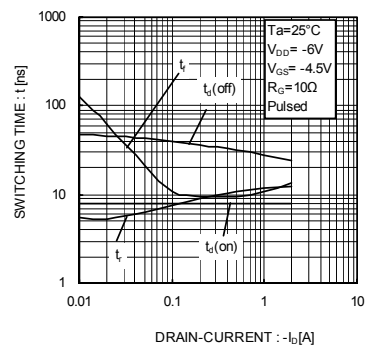


Fig.12 Switching Characteristics

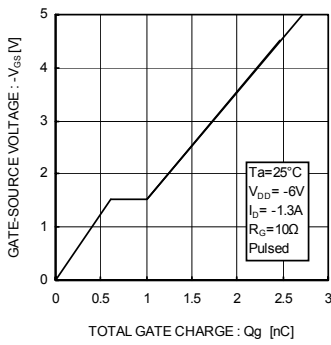


Fig.13 Dynamic Input Characteristics

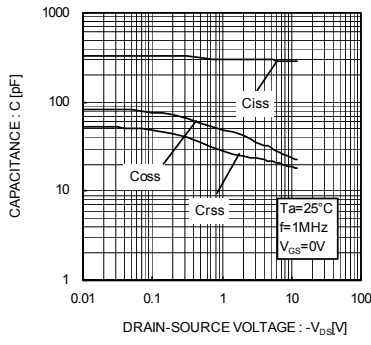


Fig.14 Typical Capacitance vs. Drain-Source Voltage

●Measurement circuits

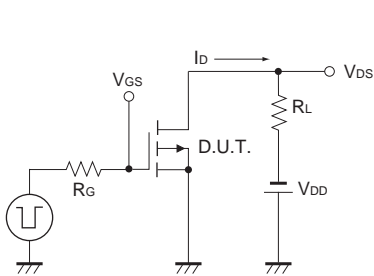


Fig.1-1 Switching time measurement circuit

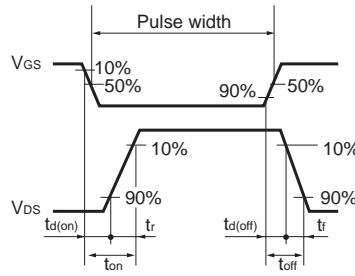


Fig.1-2 Switching waveforms

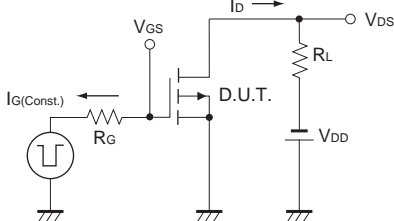


Fig.2-1 Gate charge measurement circuit

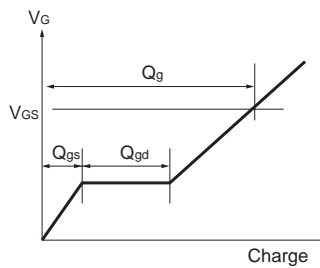


Fig.2-2 Gate charge waveform

●Notice

This product might cause chip aging and breakdown under the large electrified environment . Please consider to design ESD protection circuit.

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